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Application No.		Filing Date		Examiner	Art Unit
09/296,835		April 22, 1999		Erik Kielin	2813
pplicant(s): Ron	nald A. Weimer	, et al.			
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	In		•	Dated:	June 3, 2004
Thomas J. D'Ar					
Attorney Reg. No. DICKSTEIN SH			VIID		
2101 L Street N		N & USHINSK	I LLP		
Washington, Do					
(202) 828-2232					



Docket No.: M4065.0319/P319

(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Examiner: E. J. Kielin

Ronald A. Weimer, et al.

Application No.: 09/296,835

Art Unit: 2813

Filed: April 22, 1999

For: FABRICATION OF DRAM AND OTHER

SEMICONDUCTOR DEVICES WITH AN INSULATING FILM USING A WET RAPID

THERMAL OXIDATION PROCESS

AMENDMENT IN RESPONSE TO

OFFICE COMMUNICATION DATED MAY 17, 2004

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

This paper is in response to the PTO Office Communication dated May 17, 2004 and is fully responsive to the Office Action dated December 22, 2003. Please amend the above-identified U.S. patent application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks begin on page 6 of this paper.